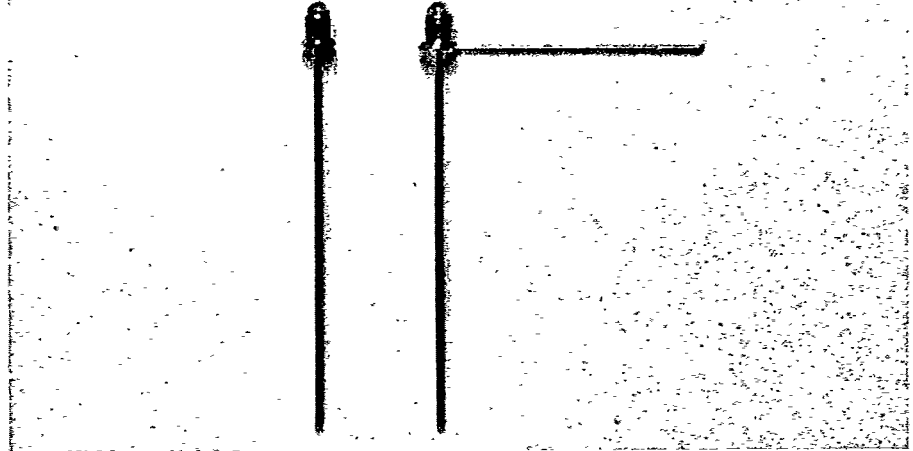




OPTO TECHNOLOGY

TYPE OT 400

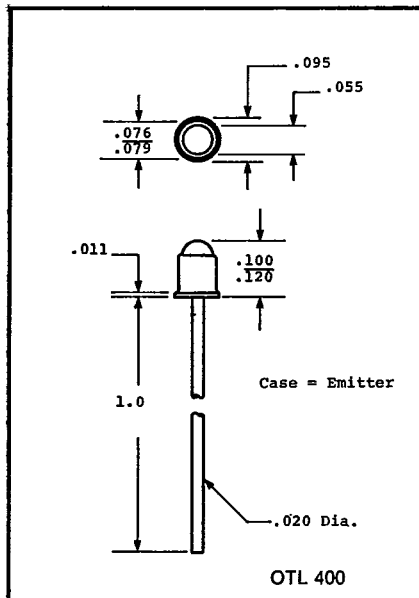
MINIATURE PHOTOTRANSISTOR



NOT ACTUAL SIZE

DESCRIPTION

Opto Technology's OT 400 Sensors feature an NPN silicon phototransistor mounted in a miniature hermetic package. The lensing effect allows an acceptance half angle of 12° measured from the optical axis to the half power point.



ELECTRICAL CHARACTERISTICS: (25°C)

		SYMBOL	MIN.	TYP.	MAX.	UNITS
Light Current*	OT400-1	I_L	1.0	—	—	mA
$V_{ce} = 5V, H = 5mw/cm^2(1)$	OT400-6	I_L	6.0	—	—	mA
Dark Current $V_{ce} = 10V, H = 0$		I_D	—	—	40	nA
Collector-Emitter Voltage		V_{ceo}	—	—	35	V
Emitter-Collector Voltage		V_{eco}	—	—	6	V
Saturation Voltage $I = 1mA$		$V_{ce} (Sat)$	—	—	.5	V
Rise or Fall Time	OT400-1	t_r, t_f	—	3	—	μS
$R_L = 100\Omega, V_{cc} = 10V$	OT400-6	t_r, t_f	—	5	—	μS
Angular Response		ϕ	—	12	—	deg.

*Special screening available upon request

(1) Light source is unfiltered tungsten bulb operating at $CT = 2870^\circ K$

Storage Temperature..... $-65^\circ C$ to $150^\circ C$

Operating Temperature..... $-65^\circ C$ to $125^\circ C$

Lead Soldering Temperature.....5 Sec. @ $240^\circ C$

